

L Number	Hits	Search Text	DB	Time stamp
1	2	5872541.pn.	USPAT; EPO; JPO; DERWENT	2004/03/12 18:02
2	3862	313/309-311,495-497.ccls.	USPAT; EPO; JPO; DERWENT	2004/03/12 18:58
3	51	313/309-311,495-497.ccls. and ("SiO.sub.2" silica "silicon oxide") and ("stannic oxide" "tin oxide" "SnO.sub.2") and (substrate near9 (sodium na))	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
4	33	313/309-311,495-497.ccls. and ("SiO.sub.2" silica "silicon oxide") and ("stannic oxide" "tin oxide" "SnO.sub.2") and (substrate near9 (sodium na)) and nm	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
7	88	phosphorus and (insulat\$3 dielectric) and electron and 313/309-311,495-497.ccls.	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
5	32	313/309-311,495-497.ccls. and ("SiO.sub.2" silica "silicon oxide") and ("stannic oxide" "tin oxide" "SnO.sub.2") and (substrate near9 (sodium na)) and nm and electron	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
6	29	313/309-311,495-497.ccls. and ("SiO.sub.2" silica "silicon oxide") and ("stannic oxide" "tin oxide" "SnO.sub.2") and (substrate near9 (sodium na)) and nm and particle	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
8	37	((phosphorus phosphor) with ("silicon dioxide" silica "sio.sub.2")) and electron and 313/309-311,495-497.ccls.	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
10	41	((phosphorus with (insulat\$3 dielectric)) bpsg) and electron and 313/309-311,495-497.ccls.	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59
11	15	((((phosphorus phosphor) with ("silicon dioxide" silica "sio.sub.2")) and electron and 313/309-311,495-497.ccls.) not ((phosphor\$2 with "sio.sub.2") and electron and 313/309-311,495-497.ccls.)	USPAT; EPO; JPO; DERWENT	2004/03/12 18:59